

DB10XS SERIES

SINGLE-PHASE SURFACE MOUNT BRIDGE RECTIFIER

产 品 规 格 确 认 书

DB101S THRU DB107S

SINGLE-PHASE GLASS PASSIVATED SILICON SURFACE MOUNT BRIDGE RECTIFIER



康比電子
HORNBY ELECTRONIC

REVERSE VOLTAGE: 50 to 1000 VOLTS

FORWARD CURRENT: 1.0 AMPERE

FEATURES

- Glass passivated chip junction
- Low forward voltage drop
- High surge overload rating of 50 Amperes peak
- Ideal for printed circuit board
- High temperature soldering guaranteed:
260°C for 10 seconds

MECHANICAL DATA

Case: Molded plastic, DB-S

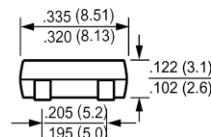
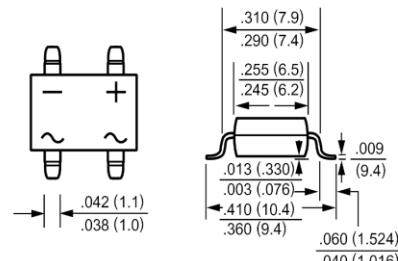
Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202,
method 208 guaranteed

Mounting position: Any

Weight: 0.02ounce, 0.4gram

DB-S



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25° ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	DB101S	DB102S	DB103S	DB104S	DB105S	DB106S	DB107S	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T _A =40°C (Note 2)	I _(AV)					1.0			Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I _{FSM}				50				Amp
Maximum Forward Voltage at 1.0A DC and 25°C	V _F				1.1				Volts
Maximum Reverse Current at T _A =25°C at Rated DC Blocking Voltage T _A =125°C	I _R				5.0	500			uAmp
Typical Junction Capacitance (Note 1)	C _J				25				pF
Typical Thermal Resistance (Note 2)	R _{θJA}				40				/W
Typical Thermal Resistance (Note 2)	R _{θJL}				15				/W
Operating and Storage Temperature Range	T _J , T _{Stg}				-55 to +150				

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Units mounted on P.C.B. with 0.5 x 0.5" (13 x 13mm) copper pads

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RATINGS AND CHARACTERISTIC CURVES

Fig. 1 - Derating Curve Output Rectified Current

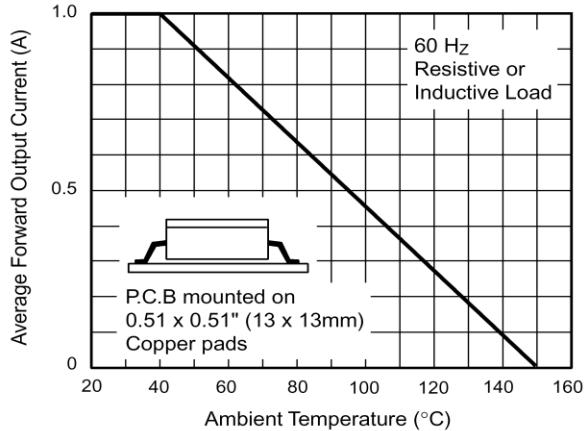


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Leg

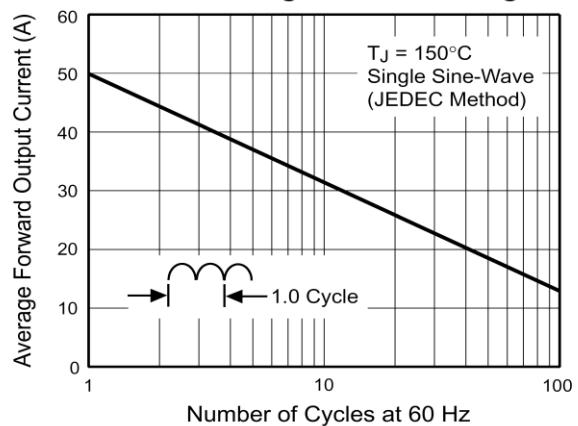


Fig. 3 - Typical Forward Characteristics Per Leg

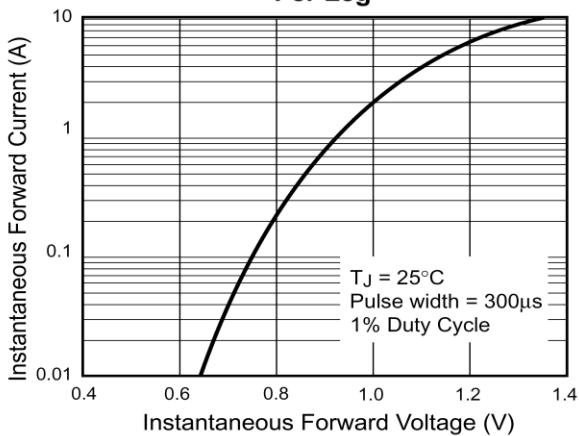


Fig. 4 - Typical Reverse Leakage Characteristics Per Leg

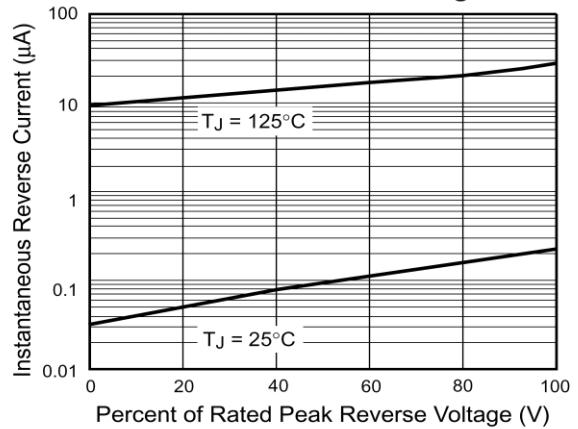


Fig. 5 - Typical Junction Capacitance Per Leg

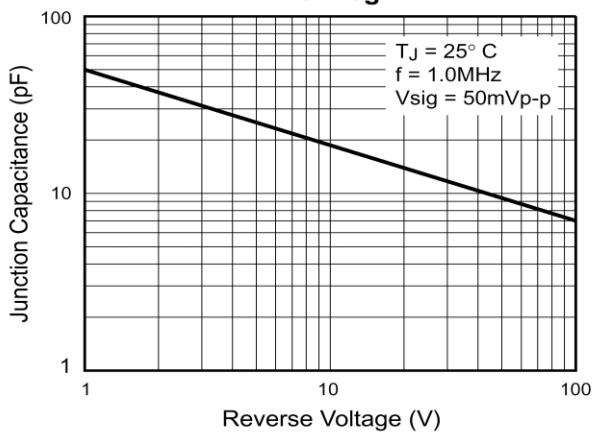


Fig. 6 - Typical Transient Thermal Impedance

